



1. General description

Planar passivated sensitive gate four quadrant triac in a SOT82 (SIP3) plastic package intended for use in general purpose bidirectional switching and phase control applications. This "series E" sensitive gate triac is intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

2. Features and benefits

- High blocking voltage capability
- Planar passivated for voltage ruggedness and reliability
- Sensitive gate
- Triggering in all four quadrants
- Direct interfacing to logic level ICs
- Direct interfacing to low power gate drive circuits
- · Low holding current for low current loads and lowest EMI at commutation
- Compact package

3. Applications

- General purpose low power motor control
- Home appliances
- Industrial process control

4. Quick reference data

Symbol	Parameter	Conditions		Values			Unit
Absolute	maximum rating						
V _{drm}	repetitive peak off-state voltage			6	00		V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 107 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>					A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>		2	25		A
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>		-	2.5	10	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>		-	4	10	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>		-	5	10	mA
		V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u>		-	11	25	mA
I _H	holding current	V _D = 12 V; T _i = 25 °C; <u>Fig. 9</u>		-	2.2	15	mA

5. Pinning information

Table 2.	Pinning info	rmation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1	·	
2	T2	main terminal 2		N
3	G	gate		
mb	T2	mounting base; main terminal 2	·~*	sym051

6. Ordering information

Table 3. Ordering inform	nation		
Type number	Package		
	Name	Description	Version
BT134-600E	SIP3	plastic single-ended package; 3-leads (in-line)	SOT82

7. Marking

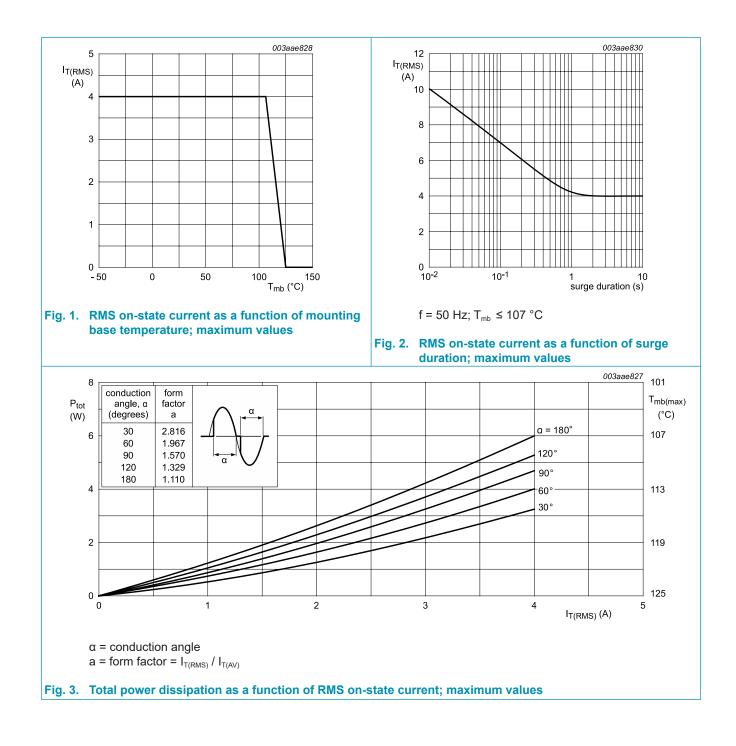
Table 4. Marking codes							
Type number	Marking codes						
BT134-600E	BT134-600E						

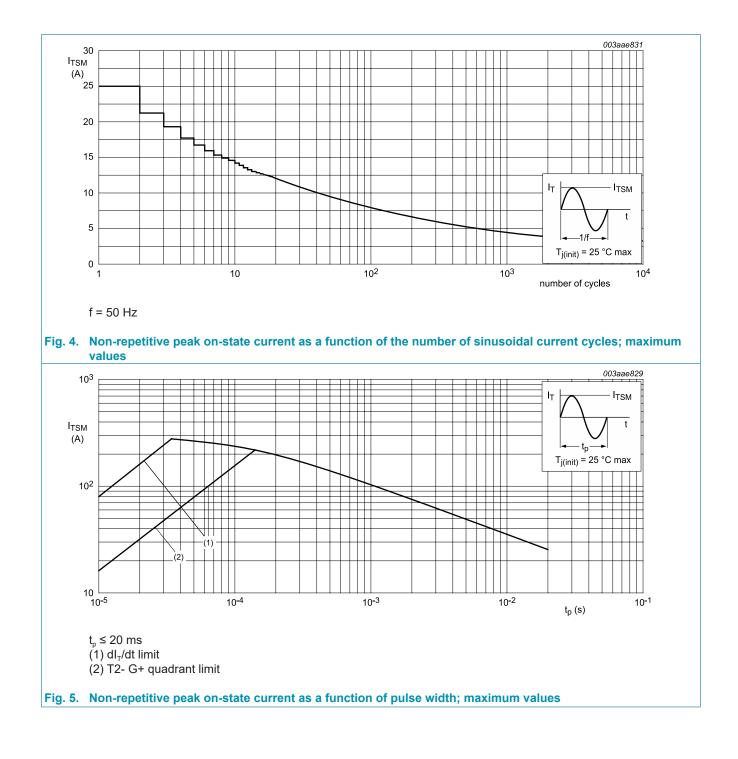
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

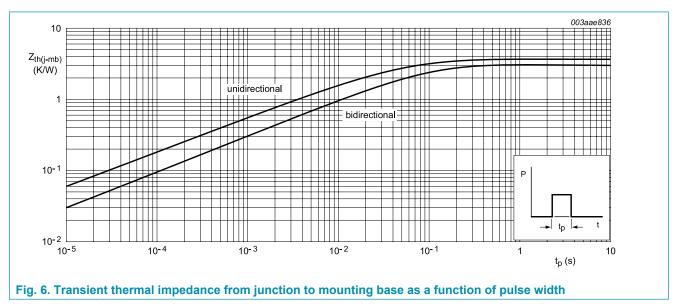
Symbol	Parameter	Conditions	Values	Unit
V _{DRM}	repetitive peak off-state voltage		600	V
I _{T(RMS)}	RMS on-state current	full sine wave; $T_{mb} \le 107 \text{ °C}$; Fig 1; Fig 2; Fig 3	4	А
I _{TSM} non-repetitive peak on- state current		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig 4; Fig 5	25	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	27	А
l ² t	I ² t for fusing	t _P = 10 ms; SIN	3.1	A ² s
dl _⊤ /dt	rate of rise of on-state	I _G = 20 mA; T2+ G+	50	A/µs
	current	I _G = 20 mA; T2+ G-	50	A/µs
		I _G = 20 mA; T2- G-	50	A/µs
		I _G = 50 mA; T2- G+	10	A/µs
I _{GM}	peak gate current		2	А
P _{GM}	peak gate power		5	W
P _{G(AV)}	average gate power	over any 20 ms period	0.5	W
T _{stg}	storage temperature		-40 to 150	°C
T _j	junction temperature		125	°C





9. Thermal characteristics

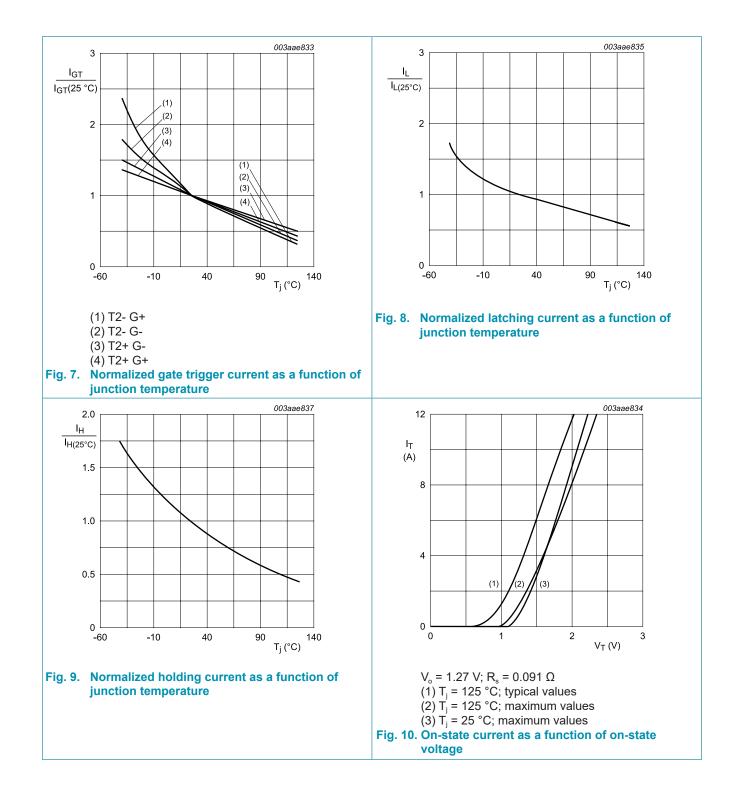
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance	half cycle; <u>Fig 6</u>	-	-	3.7	K/W
	from junction to mounting base	full cycle; <u>Fig 6</u>	-	-	3	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air	-	100	-	K/W

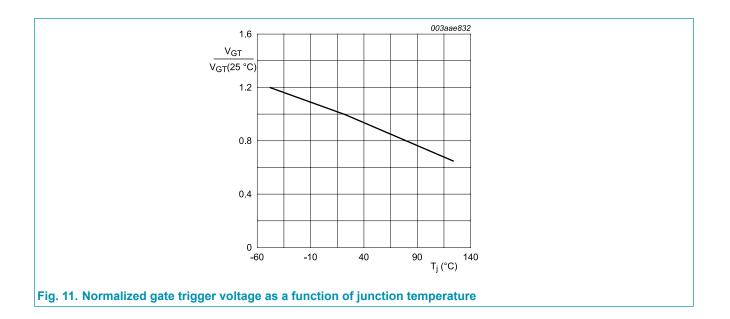


10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					_
I _{GT}	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; Fig. 7	-	2.5	10	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 7	-	4	10	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; <u>Fig. 7</u>	-	5	10	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G+};$ T _j = 25 °C; <u>Fig. 7</u>	-	11	25	mA
L	latching current	$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; <u>Fig. 8</u>	-	3	15	mA
		V_{D} = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u>	-	10	20	mA
		V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u>	-	2.5	15	mA
		V_{D} = 12 V; I _G = 0.1 A; T2- G+; T _j = 25 °C; Fig. 8	-	4	20	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	2.2	15	mA
V _T	on-state voltage	I _T = 5 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.4	1.7	V
V _{GT}	gate trigger voltage	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T}_j = 25 \text{ °C};$ Fig. 11	-	0.7	1	V
		V_{D} = 400 V; I _T = 0.1 A; T _j = 125 °C; Fig. 11	0.25	0.4	-	V
I _D	off-state current	V _D = 600 V; T _j = 125 °C	-	0.1	0.5	mA
Dynamic	characteristics					,
dV _D /dt	rate of rise of off-state voltage	$V_{DM} = 402 \text{ V}; \text{ T}_{j} = 125 \text{ °C}; (V_{DM} = 67\% \text{ of } V_{DRM});$ exponential waveform; gate open circuit	-	50	-	V/µs
t _{gt}	gate-controlled turn-on time	$V_{\rm D}$ = 600 V; I _{TM} = 6 A; I _G = 0.1 A; dI _G /dt = 5 A/µs	-	2	-	μs
gi						

BT134-600E 4Q Triac





11. Package outline

<image/>	astic single-	ended p	acka	ge; 3	lead	s (in-	line)							SO
$\begin{array}{c c c c c c c c c c c c c c c c c c c $				(]										
UNIT A b c D E e e1 L $L_1^{(1)}$ max. P Q q w mm 2.8 0.88 0.58 11.1 7.8 2.29 4.58 16.5 2.54 3.1 1.5 3.9 0.254 Note I. Terminal dimensions within this zone are uncontrolled to allow for body and terminal irregularities. OUTLINE VENDIN IEC EUROPEAN PROJECTION ISSUE DATE		4	e						2.5	5 mn				
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VERSION IEC JEDEC EIAJ PROJECTION ISSUE DATE		sions withi	in this z	one are	uncon	trolled	to allov	v for boo	dy and	termina	l irregu	larities.		
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	SOT82													97-06-11

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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